## SD05T1 Series, SZSD05T1 Series

## **ESD Protrection Diode**

## SOD-323 Diodes for ESD Protection

These surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

## **Specification Features:**

- Steady State Power Routing of 300 mW
- Peak Power 350 W (8  $\times$  20  $\mu$ s)
- Low Leakage
- Cathode Indicated by Polarity Band
- Package Weight: 4.507 mg/wmt
- Meets IEC61000-4-2 Level 4, 15 kV (Air), 8 kV (Contact)
- Meets IEC6100-4-4 Level 4, 40 A
- Meets IEC6100-4-5 (Lightning), 24 A
- Meets 16 kV Human Body Model ESD Requirements
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

## **Mechanical Characteristics:**

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94, V-0

**LEAD FINISH:** 100% Matte Sn (Tin)

**MOUNTING POSITION:** Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

Use the Device Number to order the 7 inch/3,000 unit reel. Replace the "T1" with "T3" in the Device Number to order the 13 inch/10,000 unit reel.



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**MARKING DIAGRAM** 



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SOD-323 CASE 477 STYLE 1

xx = Specific Device Code

ZA = SD05T1ZC = SD12T1

1 = Month Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>		
SD05T1G				
SZSD05T1G	SOD-323	2000/Tono 9 Bool		
SD12T1G	(Pb-Free)	3000/Tape & Reel		
SZSD12T1G				

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## SD05T1 Series, SZSD05T1 Series

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Power Dissipation @ 20 $\mu s$ (Note 1) @ $T_L \le 25^{\circ}C$	P <sub>pk</sub>	350	Watts
IEC 61000-4-2 (ESD)	Air act	±15 ±8.0	kV
IEC 61000-4-4 (EFT)		40	Α
ESD Voltage (Human Body Model (HBM) Waveform per IEC 61000-4-2)	V <sub>PP</sub>	30	kV
Total Power Dissipation on FR-4 Board (Note 2) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{ hetaJA}$	416	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

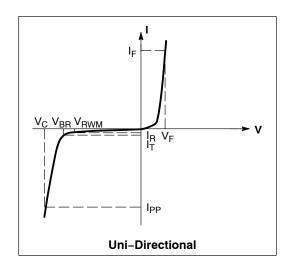
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
\*Other voltages may be available upon request.

- Nonrepetitive current pulse, per Figure 6.
- 2. FR-4 printed circuit board, single-sided copper, mounting pad 1 cm<sup>2</sup>.

## **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>					
V <sub>RWM</sub>	V <sub>RWM</sub> Working Peak Reverse Voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>					
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>					
I <sub>T</sub>	Test Current					
IF	Forward Current					
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>					



## **ELECTRICAL CHARACTERISTICS**

			V <sub>BR</sub> , Breakdown Voltage (V)			V <sub>C</sub> @ I <sub>PP</sub> = 5 A	Max I <sub>PP</sub>	V <sub>C</sub> @ Max I <sub>PP</sub>	Max Capacitance (pF)
Device	V <sub>RWM</sub> (V)	I <sub>R</sub> @ V <sub>RWM</sub> (μΑ)	Min	Max	I <sub>T</sub> mA	(Note 3) (V)	(Note 3) (A)	(Note 3) (V)	V <sub>R</sub> = 0 V f = 1.0 MHz
SD05T1G	5.0	10	6.2	7.3	1.0	9.8	24	14.5	350
SD12T1G	12	1.0	13.3	15.75	1.0	19	15	25	150

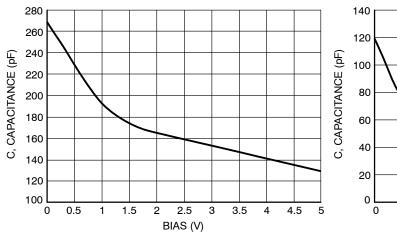
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

<sup>3.</sup>  $8 \times 20~\mu s$  pulse waveform.

<sup>\*</sup>Include SZ-prefix devices where applicable.

## SD05T1 Series, SZSD05T1 Series

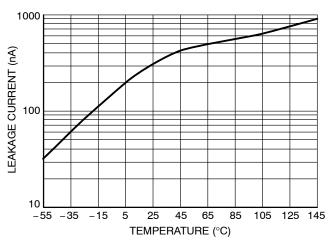
### **TYPICAL CHARACTERISTICS**



140 120 100 80 60 40 20 0 2 4 6 8 10 12 BIAS (V)

Figure 1. SD05 Typical Capacitance versus Bias Voltage

Figure 2. SD12 Typical Capacitance versus Bias Voltage



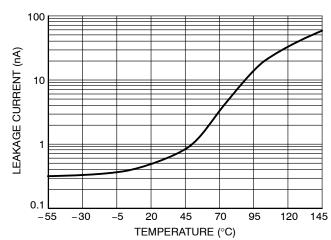
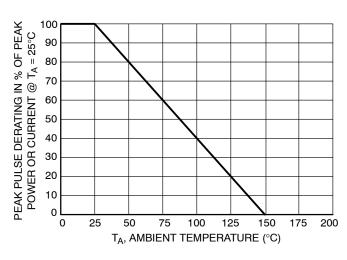


Figure 3. SD05 Typical Leakage Current versus Temperature

Figure 4. SD12 Typical Leakage Current versus Temperature



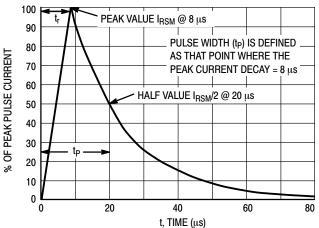
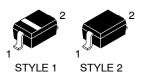


Figure 5. Pulse Derating Curve

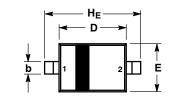
Figure 6. 8  $\times$  20  $\mu s$  Pulse Waveform

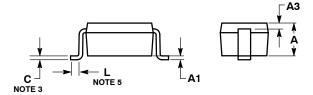


SOD-323 CASE 477-02 **ISSUE H** 

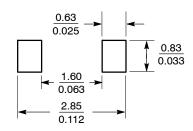
**DATE 13 MAR 2007** 

### SCALE 4:1





#### **SOLDERING FOOTPRINT\***



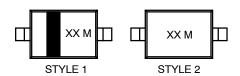
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- VIES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS.
  5. DIMENSION L IS MEASURED FROM END OF RADIUS.

	MIL	LIMETE	ERS	INCHES			
DIN	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.031	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A3	(	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016	
С	0.089	0.12	0.177	0.003	0.005	0.007	
D	1.60	1.70	1.80	0.062	0.066	0.070	
E	1.15	1.25	1.35	0.045	0.049	0.053	
L	0.08			0.003			
HE	2.30	2.50	2.70	0.090	0.098	0.105	

### **GENERIC** MARKING DIAGRAM\*



XX = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

NO POLARITY

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